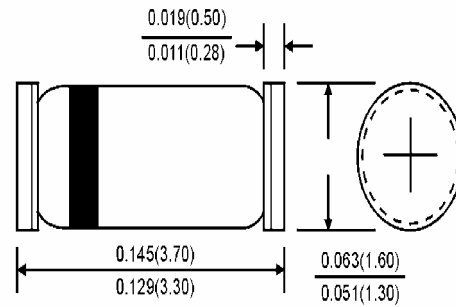


# BAV100/101/102/103

500mW Hermetically Sealed Glass  
High Voltage Switching Diodes

## MINI MELF



Dimensions in inches and (millimeters)

## Features

- ✧ High Voltage Switching Device
- ✧ Mini Melf package
- ✧ Surface device type mounting
- ✧ Hermetically sealed glass
- ✧ Compression bonded construction
- ✧ All external surface are corrosion resistant and leads are readily solderable
- ✧ RoHS compliant
- ✧ Matte Tin (Sn) lead finish
- ✧ Color band indicates Negative Polarity

## Maximum Ratings and Electrical Characteristics

Rating at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load.

For capacitive load, derate current by 20%

### Maximum Ratings

| Type Number                                                                                         | Symbol         | Value        | Units |
|-----------------------------------------------------------------------------------------------------|----------------|--------------|-------|
| Repetitive Peak Reverse Voltage                                                                     | $V_{RRM}$      | 250          | V     |
| Average Rectified Forward Current                                                                   | $I_{F(AV)}$    | 200          | mA    |
| Non- Repetitive Peak Forward Surge Current<br>Pulse Width = 1.0 Second<br>Pulse Width = 1.0 usecond | $I_{FSM}$      | 1.0<br>4.0   | A     |
| Power Dissipation                                                                                   | $P_d$          | 500          | mW    |
| Operating and Storage Temperature Range                                                             | $T_J, T_{STG}$ | -65 to + 200 | °C    |

### Electrical Characteristics

| Type Number                                                                                   | Symbol          | Min                     | Max                      | Units |
|-----------------------------------------------------------------------------------------------|-----------------|-------------------------|--------------------------|-------|
| Breakdown Voltage<br>BAV100 IR=100uA<br>BAV101 IR=100uA<br>BAV102 IR=100uA<br>BAV103 IR=100uA | $B_V$           | 60<br>120<br>200<br>250 |                          | V     |
| Forward Voltage<br>IF= 100mA                                                                  | $V_F$           |                         | 1.0                      | V     |
| Peak Reverse Current<br>BAV100 VR=50V<br>BAV101 VR=100V<br>BAV102 VR=150V<br>BAV103 VR=200V   | $I_R$           |                         | 100<br>100<br>100<br>100 | nA    |
| Thermal Resistance, Junction to Ambient                                                       | $R_{\theta JA}$ |                         | 350                      | °C/W  |
| Junction Capacitance<br>VR=0, f=1.0MHz                                                        | $C_j$           |                         | 5.0                      | pF    |
| Reverse Recovery Time (Note)                                                                  | $t_{rr}$        |                         | 50                       | nS    |

Notes: Reverse Recovery Test Conditions: IF=IR=30mA, Irr=3mA, RL=100Ω.

RATINGS AND CHARACTERISTIC CURVES (BAV100/101/102/103)

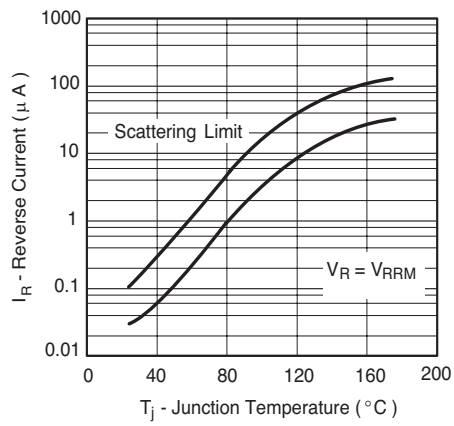


Fig. 1 Reverse Current vs. Junction Temperature

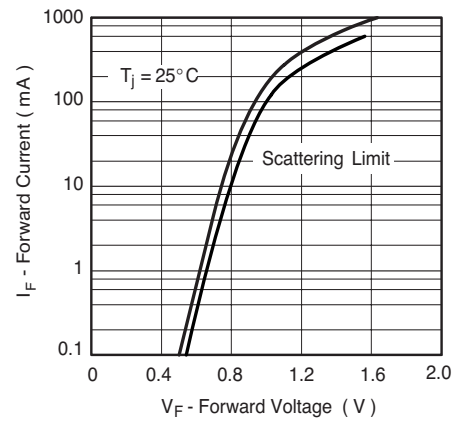


Fig. 2 Forward Current vs. Forward Voltage

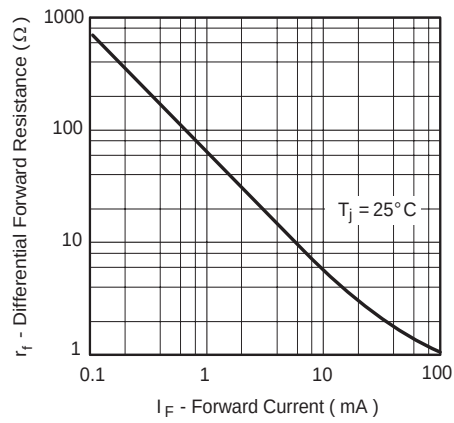


Fig. 3 Differential Forward Resistance vs. Forward Current